

Nanocomposites and nanomaterials

Diamond-tungsten carbide nanocomposite as working element for fine turning

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The diamond-tungsten carbide nanocomposite was produced by HP-HT sintering of diamond nanopowder with nanoparticles of a tungsten-containing substance. The mixtures were prepared by chemical method [1]. We have used ASM5 0.1/0 statically synthesized diamond nanopowder, and a tungsten trioxide nanopowder as components of the mixtures. Before sintering the mixture was heat-treated in a hydrogen atmosphere.

According to X-ray analysis, the sintered samples include WC tungsten carbide and WO_3 tungsten oxide. Tungsten carbide was formed as results of both the direct interaction of diamond with tungsten and reactions in the W–C–O system [2]. Nanoparticles of tungsten carbide formed in voids between the diamond nanoparticles are chemically bonded with them. This improves physico-mechanical properties of the composite. The composite combines high hardness ($HV = 25$ GPa), fracture toughness ($K_{IC} = 6.6$ MPa·m^{1/2}), and thermal stability (at 1370 K $K_{ts} = 0.86$).

Fine turning of aluminum alloy A6 sample of diameter of 60–65 mm was made. Round cutting insert of nanocomposite of diameter of 7 ± 0.025 mm served as the working element of the tool. Fixation was carried out mechanically. Cutter had a rake angle γ of 0° ; flank angle α of 10° . Feed was 0.25 mm/rev and cutting speed was 4.5 m/s. The formed surface has a surface roughness Ra of 0.4 μ m and waviness Raw of 0.7 μ m.

1. Novikov M.V., Bochechka O.O., Nazarchuk S.M., Gavrilova V.S., Oleinik G.S., Romanko L.O., Sveshnikov I.A., Zabolotnyi S.D. Patent of Ukraine 50931 // Byull. – 2010. – 12.

2. Nazarchuk S.N., Bochechka A.A., Gavrilova V.S. at al. The diamond-tungsten carbide polycrystalline composite material // J. Superhard Materials.–2011.–33, N. 1.–P. 1–12.